AnserRF

Internal Matching GaAs Power Amplifier Module

ACMI027031-P40

S-band matched GaAs power amplifier module

Features:

Frequency: 2.7~3.1GHz

Saturated Output Power: Psat≥40dBm

PowerGain: Gain≥24dB Efficiency: η=45%(type)

Port Matching: $Z_{in}/Z_{out} = 50\Omega$

Description:

ACMI027031-P40 is an internal matching GaAs power amplifier module, which adopts advanced co-planar internal matching MCM and thin film circuit technology. The typical working frequency range is 2.7~3.1GHz. This device can be used in different RF/Microwave system and subsystem. The high output power level, high efficiency and wide operating temperature range can make application very flexible.

Maximun Ratings (TC=25°C, Not recommended working under this condition):

| | Symbol | Value | Unit |
|--------------------------------------|-----------------|-------------|------|
| Voltage between source and drain | V _{DS} | 11 | V |
| Voltage between gate and source | V _{GS} | -3 | V |
| Storage Temperature Range | T_{stg} | -65 to +150 | °C |
| Drain and Source Channel Temperature | Tch | 150 | °C |

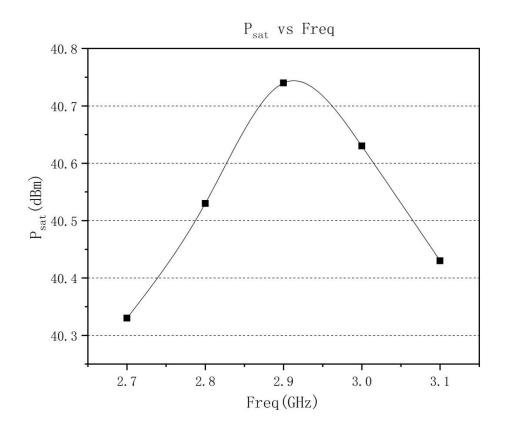


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Electrical Characteristics:

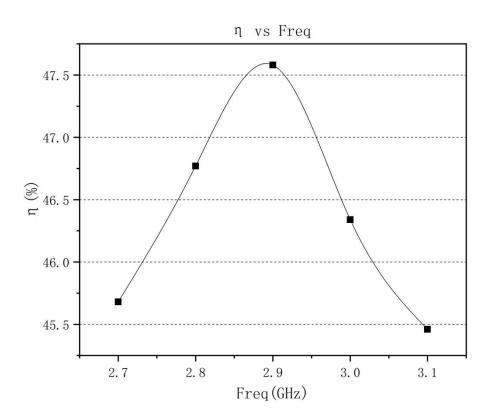
| | | | Value | | | |
|------------------------|--------|---|-------|-----|------|------|
| | Symbol | Test condition | Min | Тур | Max | Unit |
| Drain Current | ldsr | Vds=10V CW. Pin: 16dBm Freq: 2.7~3.1GHz | - | 2.2 | - | А |
| Saturated Output Power | Psat | | 40 | - | - | dBm |
| Gain | Gp | | 24 | - | - | dB |
| Efficiency | η | | - | 45 | - | % |
| Gain Flatness | ΔG | | -0.8 | - | +0.8 | dB |

Typical Curve:

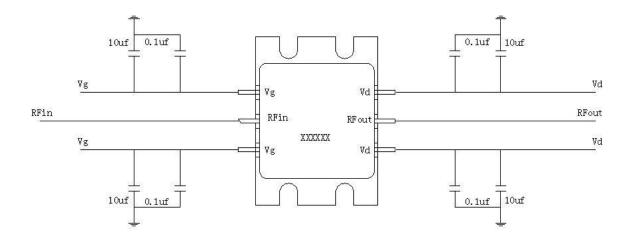




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Application Circuit:



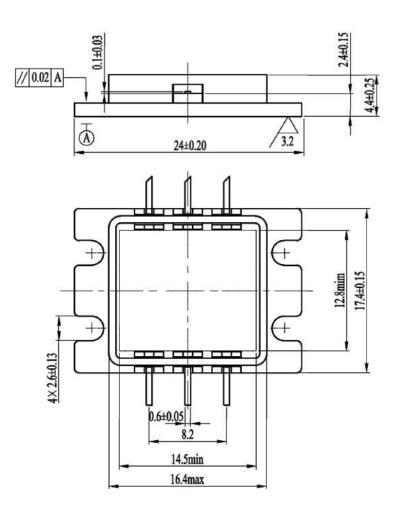


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ESD Level:

| ESD | Class III | 2000V |
|-----|-----------|-------|
|-----|-----------|-------|

Outline:



Precautions for use:

- Pay attention to drying transportation and storage.
- Pay attention to anti-static during chip use and assembly, and wear grounding anti-static bracelet.
- When powering up, first apply grid power then add leakage.